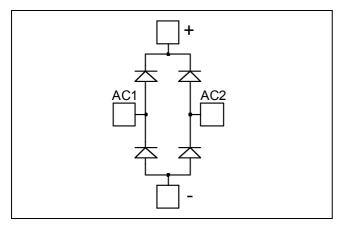


# **APTDF200H100G**

# Diode Full Bridge Power Module



# $V_{RRM} = 1000V$ $I_{C} = 200A$ @ Tc = 70°C

### Application

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

#### Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

#### Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

## All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

## Absolute maximum ratings

Symbol	Parameter				Max ratings	Unit
V <sub>R</sub>	Maximum DC reverse Voltage			1000	V	
V <sub>RRM</sub>	Maximum Peak Repetitive Revers	e Voltage			1000	v
I <sub>F(AV)</sub>	Maximum Average Forward	Dute mul	500/	$T_C = 25^{\circ}C$	255	
	Current	Duty cycl	e = 50%	$T_C = 70^{\circ}C$	200	А
I <sub>F(RMS)</sub>	RMS Forward Current	Duty cycle = 50%		$T_C = 45^{\circ}C$	255	A
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current 8.3ms		$T_C = 45^{\circ}C$	1500		

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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## **Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
$V_{\rm F}$	Diode Forward Voltage	$I_F = 200A$			2.1	2.7	
		$I_F = 300A$			2.3		V
		$I_{\rm F} = 200 {\rm A}$	$T_{j} = 125^{\circ}C$		1.7		
т	Maximum Reverse Leakage Current	$V_{R} = 1000V$ $T_{i} = 25^{\circ}C$ $T_{j} = 125^{\circ}C$	$T_i = 25^{\circ}C$			100	
I <sub>RM</sub>			$T_{j} = 125^{\circ}C$			600	μA
CT	Junction Capacitance	$V_{R} = 1000V$			240		pF

# **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
t <sub>rr</sub>	Reverse Recovery Time	$I_F=1A, V_R=30V$ di/dt = 200A/ $\mu$ s	$T_j = 25^{\circ}C$		43		ns
t <sub>rr</sub>	Reverse Recovery Time	Varu Timo	$T_j = 25^{\circ}C$		290		ns
۲r	Reverse Recovery Time		$T_{j} = 125^{\circ}C$		340		
Q <sub>rr</sub>	Reverse Recovery Charge	$I_{\rm F} = 200 \text{A}$ $V_{\rm R} = 667 \text{V}$ $di/dt = 400 \text{A}/\mu \text{s}$	$T_j = 25^{\circ}C$		1.37		μC
Qrr	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		8.1		μΟ
I <sub>RRM</sub>	Reverse Recovery Current		$T_j = 25^{\circ}C$		12		А
IRRM	Reverse Recovery Current		$T_{j} = 125^{\circ}C$		36		
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 200A$ $V_R = 667V$ $di/dt = 2000A/\mu s$			160		ns
Q <sub>rr</sub>	Reverse Recovery Charge		$T_j = 125^{\circ}C$		14.2		μC
I <sub>RRM</sub>	Reverse Recovery Current				140		А

## Thermal and package characteristics

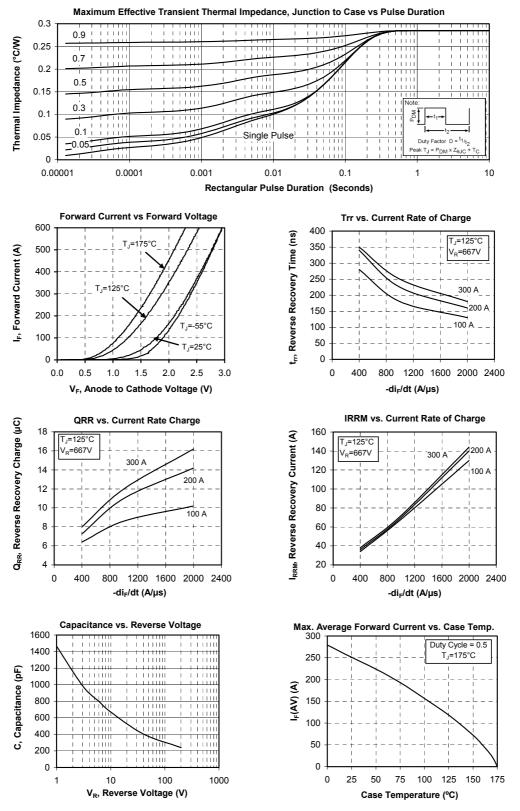
Symbol	Characteristic			Min	Тур	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance					0.285	°C/W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range			-40		175	°C
T <sub>STG</sub>	Storage Temperature Range			-40		125	
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	19.111
Wt	Package Weight					300	g

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# **APTDF200H100G**

#### **Typical Performance Curve**

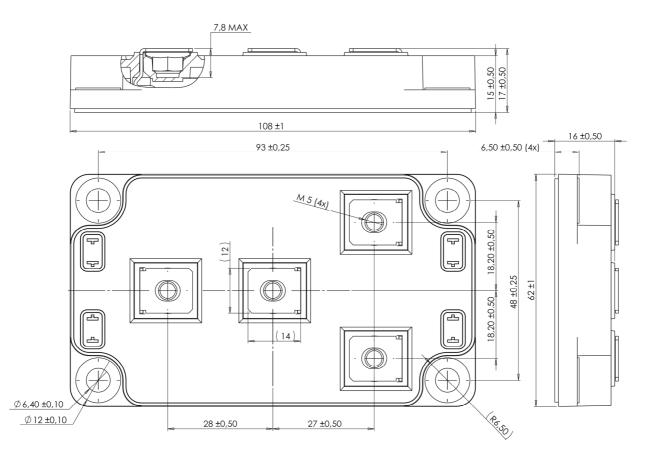


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## SP6 Package outline (dimensions in mm)



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